Submicrometer-wide amorphous and polycrystalline anatase TiO$_2$ waveguides for microphotonic devices

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Abstract: We demonstrate amorphous and polycrystalline anatase TiO$_2$ thin films and submicrometer-wide waveguides with promising optical properties for microphotonic devices. We deposit both amorphous and polycrystalline anatase TiO$_2$ using reactive sputtering and define waveguides using electron-beam lithography and reactive ion etching. For the amorphous TiO$_2$, we obtain propagation losses of 0.12 ± 0.02 dB/mm at 633 nm and 0.04 ± 0.01 dB/mm at 1550 nm in thin films and 2.6 ± 0.5 dB/mm at 633 nm and 0.4 ± 0.2 dB/mm at 1550 nm in waveguides. Using single-mode amorphous TiO$_2$ waveguides, we characterize microphotonic features including microbends and optical couplers. We show transmission of 780-nm light through microbends having radii down to 2 μm and variable signal splitting in microphotonic couplers with coupling lengths of 10 μm.

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References and links


1. Introduction

The development of nanoscale optical waveguides with low losses has led to miniature, efficient photonic devices for applications in the fields of communications, computing, metrology, and sensing [1–8]. Nanoscale waveguides strongly confine light by utilizing high-refractive-index-contrast materials, resulting in high optical intensities for efficient nonlinear light-matter interactions [9–11], small bending radii, and microscale device footprints [12, 13]. Furthermore, controlling nanoscale features enables one to engineer critical waveguide properties, such as the number of supported modes, the strength of signal coupling between adjacent waveguides, effective nonlinearity, and waveguide dispersion [14, 15].

Standard nanoscale waveguide materials, such as silica and silicon, have limitations despite their low cost and compatibility with current photonic and electronic platforms. Fiber-based silica nanowires have limited scalability due to labor-intensive assembly [12]. Meanwhile, silicon, a scalable material with mature fabrication processes, offers transparency only at wavelengths above 1.1 $\mu$m. Limited transparency inhibits its use in emerging applications such as quantum photonics, where promising single-photon sources emit at visible wavelengths [16]. Silicon also exhibits strong two-photon absorption at telecommunications wavelengths, which leads to free-carrier absorption and prohibits many nonlinear devices [11, 17, 18]. Therefore, we require complimentary nanoscale waveguide materials to meet the demands of future visible and near infrared linear and nonlinear microphotonic systems.

Recently, titanium dioxide (TiO$_2$) has attracted attention as a prospective photonic material [19–25]. Amorphous and polycrystalline TiO$_2$ thin films can be deposited at low temperatures (< 650 K) using conventional, scalable methods [26], allowing for straightforward integration with other on-chip devices [27]. TiO$_2$ has a high refractive index ($n$=2.4), which allows for high-refractive-index-contrast waveguides and strong light confinement. Due to its large bandgap ($E_g$ = 3.1 eV), TiO$_2$ is transparent over a broad wavelength range that includes the visible and near-infrared. In addition, TiO$_2$ is a promising nonlinear photonic material, having a high nonlinearity (≥ 25 times higher than silica) [28–30] and low two-photon absorption for wavelengths above 800 nm [30]. This combination of properties puts TiO$_2$ into a similar class as silicon nitride; however, TiO$_2$ exhibits both a higher linear refractive index (2.4 for TiO$_2$ versus 2.0 for silicon nitride at 800 nm) and nonlinear refractive index ($9 \times 10^{-19}$ m$^2$/W for bulk rutile TiO$_2$ versus $2.4 \times 10^{-19}$ m$^2$/W for silicon nitride) [28, 31].

Amorphous TiO$_2$ waveguides on oxidized silicon [22, 24] and waveguides formed in single-crystal rutile [23, 25] have been demonstrated. The reported amorphous waveguide structures were limited to large dimensions (> 1 $\mu$m) [22] or only investigated for visible-wavelength operation [24]. For practical on-chip devices, such waveguides must have submicrometer dimensions to support single-mode operation. Small dimensions are also necessary for flexibility in the design of basic features such as waveguide bends and optical-couplers on the microscale. In addition, anatase microphotonic waveguides have not been developed, despite having a higher reported nonlinearity [29] and requiring lower fabrication temperatures than crystalline rutile waveguides.

In this paper, we report on TiO$_2$ strip waveguides with submicrometer dimensions and promising optical properties for on-chip photonic devices. We fabricate both amorphous and polycrystalline anatase TiO$_2$ thin films and compare their structural and optical properties. We
then fabricate strip waveguides and measure their propagation losses at visible and near-infrared wavelengths. Finally, we investigate microphotonic features to assess the prospective application of TiO$_2$ waveguides in photonic devices.

2. TiO$_2$ thin films

2.1 Thin-film deposition

We deposit TiO$_2$ thin films on oxidized silicon substrates (3-μm-thick SiO$_2$) using reactive radio frequency (RF) magnetron sputtering. We prepare 0.25-μm-thick TiO$_2$ films under the conditions summarized in Table 1. Films deposited at a substrate temperature of 290 K and 625 K yield amorphous and anatase TiO$_2$ thin-films, respectively [26]. We select optimal O$_2$ flow rates and RF powers to obtain stoichiometric, highly transparent TiO$_2$ thin films [21].

<table>
<thead>
<tr>
<th>Deposition Parameter</th>
<th>Amorphous TiO$_2$</th>
<th>Anatase TiO$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Temperature (K)</td>
<td>290</td>
<td>625</td>
</tr>
<tr>
<td>Pressure (mTorr)</td>
<td>2</td>
<td>2</td>
</tr>
<tr>
<td>Ar flow (sccm)</td>
<td>40</td>
<td>40</td>
</tr>
<tr>
<td>O$_2$ flow (sccm)</td>
<td>4.4</td>
<td>20</td>
</tr>
<tr>
<td>RF power (W)</td>
<td>158</td>
<td>200</td>
</tr>
<tr>
<td>Time (min.)</td>
<td>300</td>
<td>1390</td>
</tr>
</tbody>
</table>

2.2 Thin-film characterization

We determine the crystalline structure of the TiO$_2$ thin films using Raman spectroscopy. To avoid background signal from the silicon substrate, we measure Raman spectra of thin films deposited on a glass substrates using identical deposition parameters, as shown in Fig. 1 (we observe similar spectra for the films deposited on oxidized silicon substrates, with additional silicon peaks at 300 and 519 cm$^{-1}$). For films deposited at 290 K, we observe no Raman peaks (Fig. 1, top) which indicates that the TiO$_2$ phase is predominantly amorphous. Meanwhile, films deposited at 625 K display a strong peak at 144 cm$^{-1}$, and additional peaks at 194, 399, 514 and 639 cm$^{-1}$ (Fig. 1, bottom). We do not observe any of the peaks near 447, 612, or 826 cm$^{-1}$ associated with the Raman spectrum of rutile (which also includes a relatively weak peak around 143 cm$^{-1}$) [32]. The observed Raman peaks closely match those measured at 144, 197, 399, 516, and 639 cm$^{-1}$ in anatase single crystals [33], indicating that the TiO$_2$ phase is primarily anatase.

In order to compare the surface morphology of the thin films, we use scanning electron microscopy (SEM) and atomic force microscopy (AFM). Scanning electron micrographs of the surface of the films (Figs. 2(a) and 2(b)) show that the amorphous structure is granular, while the anatase film consists of densely packed nanocrystals. AFM scanning images, obtained in non-contact alternating current mode with a 9-nm-radius cantilever tip, reveal root mean square (RMS) roughness of 0.4 and 2.7 nm for the amorphous and anatase films, respectively (Figs. 2(c) and 2(d)).

We measure the optical properties of both TiO$_2$ films in the visible and near-infrared spectrum using a variable angle prism coupling system [34]. Table 2 summarizes the refractive indices of the TiO$_2$ films at 633, 826, 1310 and 1550 nm measured using transverse-electric (TE) polarized light. Both films have refractive indices of around 2.4 at 826 nm, with the anatase film having a slightly higher refractive index. Measurements using transverse-magnetic (TM) polarized light at 826 nm reveal a slight birefringence for both films, the TM indices being 0.006 and 0.012 higher in the amorphous and anatase films, respectively.
Fig. 1. Raman spectra of TiO$_2$ thin-films deposited by reactive RF magnetron sputtering at 290 K (top) and 625 K (bottom). The film deposited at 290 K has no measurable Raman peaks, indicating an amorphous structure, while the film deposited at 625 K shows peaks at 144, 194, 399, 514, and 639 cm$^{-1}$, which correspond to the anatase crystalline phase of TiO$_2$.

Table 2 also shows the thin-film propagation losses measured by scanning a fiber along the coupled planar waveguide mode normal to the surface of the film. Using a germanium detector, we collect scattered light versus position and fit the data to an exponential curve. The anatase films exhibit losses ranging from $>2.0$ dB/mm at 633 nm (beyond the measurable limit of the prism coupling system) to $0.42 \pm 0.08$ dB/mm at 1550 nm. The amorphous TiO$_2$ thin-film propagation losses are significantly lower and are less wavelength-dependent, varying from $0.12 \pm 0.02$ dB/mm at 633 nm to $0.04 \pm 0.01$ dB/mm at 1550 nm.

Fig. 2. Surface morphology of TiO$_2$ thin films: SEM images of (a) amorphous and (b) polycrystalline anatase thin-film surfaces; and AFM surface scans of (c) amorphous and (d) polycrystalline anatase thin-films showing RMS roughness of 0.4 and 2.7 nm, respectively.
Table 2. Refractive Indices and Propagation Losses of TiO$_2$ Thin Films

<table>
<thead>
<tr>
<th>Wavelength (nm)</th>
<th>Amorphous TiO$_2$</th>
<th>Anatase TiO$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>Refractive Index</td>
<td>Propagation Loss (dB/mm)</td>
<td>Refractive Index</td>
</tr>
<tr>
<td>633</td>
<td>2.426</td>
<td>0.12</td>
</tr>
<tr>
<td>826</td>
<td>2.372</td>
<td>0.06</td>
</tr>
<tr>
<td>1310</td>
<td>2.323</td>
<td>0.04</td>
</tr>
<tr>
<td>1550</td>
<td>2.315</td>
<td>0.04</td>
</tr>
</tbody>
</table>

*The films are 0.25 μm thick, consisting of amorphous and polycrystalline anatase TiO$_2$ on oxidized silicon substrates. Both indices and losses are determined by prism coupling using TE-polarization. We estimate an uncertainty of ± 0.002 for the refractive index measurements and ± 20% for the loss measurements.

3. Submicrometer-wide TiO$_2$ waveguides

3.1 Waveguide fabrication

We apply standard top-down fabrication methods to define submicrometer-wide waveguides in our amorphous and anatase TiO$_2$ thin films. First, we expose the waveguide pattern into a 300-nm-thick positive electron-beam (e-beam) resist layer (ZEP) on top of the TiO$_2$ film using a 100-keV electron-beam lithography system. The applied e-beam parameters include a $300 \times 300$ μm$^2$ write window, a beam current of 100 pA, and a dose of 400 μC/cm$^2$. After developing the exposed resist, we deposit a 50-nm-thick chromium film by e-beam evaporation and perform metal lift-off to form a metal etch mask. We then transfer the metal pattern into the TiO$_2$ film using electron cyclotron resonance reactive ion etching. The etch parameters include a CF$_4$ and H$_2$ gas mixture in a ratio of 4:1, a microwave power of 300 W, a substrate power of 150 W, and a chamber pressure of 5 mTorr. Using surface profilometry, we find that the etch rates of the amorphous and anatase films are approximately 50 and 60 nm/min, respectively. After etching, we remove the remaining metal mask using Cr-etchant, and apply a 1.6-μm-thick fluoropolymer top-cladding layer ($n = 1.39$). Finally, we cleave the chips to prepare waveguide end-facets.

Figures 3(a) and 3(b) show scanning electron micrographs of the resulting amorphous and anatase TiO$_2$ waveguides (without top-cladding), respectively. Both types of waveguides have relatively smooth, uniform sidewalls with slopes of approximately 75°. The cross-section of the anatase TiO$_2$ waveguide facet reveals the TiO$_2$ core to consist of close-packed vertical nanocrystalline columns (Fig. 2(b)).

Fig. 3. SEM images of 0.3-μm-wide (a) amorphous and (b) polycrystalline anatase TiO$_2$ waveguides fabricated on oxidized silicon wafers using e-beam lithography and reactive ion etching.

3.2 Waveguide characterization

We investigate light transmission in 5-mm-long S-shaped waveguides with widths of 0.2, 0.3, 0.4, and 0.5 μm. The selected waveguide dimensions support guided modes in the wavelength...
range 633–1550 nm. We chose a minimum bend radius of 60 μm to avoid significant bend-induced losses. Using a commercial finite-difference eigenmode solver, we determine that all waveguides are multimode at 633 nm, single-mode at 780 nm for widths of ≤ 0.3 μm (amorphous) and 0.2 μm (anatase), and single-mode at 1550 nm for widths of ≥ 0.4 μm. Widths below 0.4 μm do not support a guided mode at 1550 nm.

We measure the optical propagation losses of the TiO$_2$ strip waveguides at 633, 780 and 1550 nm using the top-view camera method [35]. Light from a 633-nm HeNe, 780-nm diode, or a 1550-nm diode laser source is aligned and focused onto the input facets of the waveguides using an objective lens (633 and 780 nm) or lensed fiber (1550 nm) mounted on a piezoelectric-motor-controlled XYZ stage. We adjust the polarization of the incident light using a half-wave plate and a polarizer prior to the objective lens (633 and 780 nm) and a paddle-based polarization controller before the lensed fiber (1550 nm). We capture images using microscope-mounted CMOS (633 and 780 nm) and InGaAs (1550 nm) cameras and determine the transmission through the TiO$_2$ waveguides by analyzing the relative intensity of scattered light along the waveguides in the resulting images.

In Fig. 4 we show representative top-view camera images of visible and infrared light propagation in our amorphous (Figs. 4(a), 4(c) and 4(e)) and polycrystalline anatase TiO$_2$ waveguides. The waveguides are 0.2-μm wide (a–d) and 0.5-μm wide (e and f).

In Fig. 4 we show representative top-view camera images of visible and infrared light propagation in our amorphous (Figs. 4(a), 4(c) and 4(e)) and polycrystalline anatase TiO$_2$ waveguides. The propagation loss data corresponding to the representative images is shown in Figs. 5(a) and 5(b). Table 3 summarizes the propagation-loss data measured for different waveguide widths. The amorphous losses are considerably lower than the anatase losses at 633 and 780 nm. The uncertainty in the fit for the InGaAs camera measurements is rather high (± 50%) due to the large relative background intensities in the
images. Therefore, we measure similar losses at 1550 nm in both types of TiO$_2$ waveguide within the experimental uncertainty.

![Fig. 5. Propagation losses in (a) amorphous and (b) polycrystalline anatase TiO$_2$ strip waveguides measured using the top-view camera method. The input light is TE-polarized and the waveguide widths are 0.2 µm (633 and 780 nm) and 0.5 µm (1550 nm).](image)

Table 3. Propagation Losses in Amorphous and Anatase TiO$_2$ Waveguides*

<table>
<thead>
<tr>
<th>Wavelength (nm)</th>
<th>Waveguide Width (µm)</th>
<th>Amorphous TiO$_2$</th>
<th>Anatase TiO$_2$</th>
</tr>
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<tbody>
<tr>
<td>633</td>
<td>0.2</td>
<td>3.0</td>
<td>5.8</td>
</tr>
<tr>
<td></td>
<td>0.3</td>
<td>2.9</td>
<td>4.8</td>
</tr>
<tr>
<td></td>
<td>0.4</td>
<td>2.6</td>
<td>6.1</td>
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<tr>
<td></td>
<td>0.5</td>
<td>3.2</td>
<td>4.8</td>
</tr>
<tr>
<td>780</td>
<td>0.2</td>
<td>1.4</td>
<td>3.5</td>
</tr>
<tr>
<td></td>
<td>0.3</td>
<td>2.2</td>
<td>3.5</td>
</tr>
<tr>
<td></td>
<td>0.4</td>
<td>1.4</td>
<td>3.1</td>
</tr>
<tr>
<td></td>
<td>0.5</td>
<td>0.9</td>
<td>3.8</td>
</tr>
<tr>
<td>1550</td>
<td>0.4</td>
<td>0.5</td>
<td>0.3</td>
</tr>
<tr>
<td></td>
<td>0.5</td>
<td>0.4</td>
<td>0.4</td>
</tr>
</tbody>
</table>

*Measurement performed using the top-view camera method (TE-polarization). The uncertainty is ± 20%, ± 20%, and ± 50% for the 633-, 780-, and 1550-nm measurements, respectively.

4. TiO$_2$ microphotonic features

4.1 Design and fabrication of microphotonic features

As a proof of principle, we investigate microphotonic features at 780 nm, near TiO$_2$’s half-bandgap and where nonlinear optical devices are feasible in bulk rutile TiO$_2$ [30]. We base our devices on a 0.3-µm-wide amorphous TiO$_2$ waveguide, which supports a single, well-confined TE-mode and has lower losses than similar anatase waveguides around 800 nm. To investigate waveguide bending losses, we fabricate waveguides with multiple bends having radii of 1–20 µm. In addition, we fabricate optical couplers consisting of two waveguides with adiabatic sine-bends into and out of a parallel coupling region. The spacing of the coupling region is 0.2 µm and its length, $L$, varies from 0 to 4 µm. We measure the transmission characteristics of the bends and optical couplers using the top-view camera method.

4.2 Micro-bends

Figure 6 summarizes the measurements and characterization of the TiO$_2$ microbends. Figure 6(a) shows the simulated electric field profile of the fundamental 780-nm TE mode confined...
by the amorphous-TiO$_2$ waveguide. In Fig. 6(b), we display a top-view SEM image of a representative TiO$_2$ waveguide with microbends having radii $r$ of 5 $\mu$m prior to cladding layer deposition. In Fig. 6(c), we show camera images of light transmission through cladded microbend features with $r = 20$ $\mu$m (top), 10 $\mu$m (middle) and 5 $\mu$m (bottom). Figure 6(d) displays the measured transmission for varying $r$. The plot shows a minimal change in transmission as $r$ is decreased to a value of 3 $\mu$m. At $r = 2$ $\mu$m we observe a change in transmission of $-9$ dB that corresponds to an added loss of $< 1$ dB/90° bend. For $r = 1$ $\mu$m, the transmission is below the measurable limit ($-40$ dB).

4.3 Optical-couplers

Figure 7(a) displays an SEM image of an optical-coupler (prior to cladding deposition) with a parallel interaction length $L = 4$ $\mu$m. Figure 7(b) shows optical images of light transmission in couplers with $L = 0$ $\mu$m (top), $L = 2$ $\mu$m (middle) and $L = 4$ $\mu$m (bottom). By measuring the scattered intensity in each output branch of the coupler ($I_{\text{upper}}$ and $I_{\text{lower}}$) we determine splitting ratios $I_{\text{upper}}/(I_{\text{upper}} + I_{\text{lower}})$ of 0.3, 0.6, and 0.9, respectively.
5. Discussion

We show that by adjusting substrate temperature, oxygen flow rate and RF sputtering power, we can deposit waveguide-quality amorphous and polycrystalline-anatase TiO$_2$ thin films. At visible and near-infrared wavelengths, our amorphous TiO$_2$ thin films exhibit significantly lower propagation losses. The difference in propagation loss is most evident in the visible. In the 0.25-μm-thick films prepared for this study, we observe a pronounced visible streak of light across tens of mm in the amorphous film, but observe no measureable 633-nm-light propagation in the polycrystalline film. We partially attribute the difference in loss to the larger surface roughness in the anatase thin film. Despite having higher thin-film losses, the anatase phase of TiO$_2$ offers potential advantages for microphotonic devices in terms of greater thermal stability [36], higher refractive index, and higher nonlinearity [29]. Reduced nanocrystal size and smoother surfaces may lead to lower losses in the polycrystalline films.

We also demonstrate a suitable method for fabricating submicrometer-wide strip waveguides using both types of TiO$_2$ thin film. The amorphous TiO$_2$ strip waveguides have lower propagation losses at 633 and 780 nm than the anatase waveguides. As with the thin films, the difference is most significant at 633 nm, where we have recently demonstrated amorphous TiO$_2$ microring resonators for visible-light systems [24]. In both amorphous and polycrystalline waveguides, we measure losses on the order of 0.3–0.5 dB/mm at 1550 nm, which are comparable to those initially reported in other high-refractive-index-contrast photonic waveguides [2, 37, 38]. The comparable losses at 1550 nm can be explained by the reduced influence of surface and edge roughness, and the low optical confinement within the TiO$_2$ core (< 40%) whereby the majority of light propagates in the low-loss cladding layers.

The measured strip-waveguide propagation losses are sufficiently low for microphotonic devices requiring μm and mm waveguide lengths. However, we observe significantly higher propagation losses in our TiO$_2$ strip waveguides compared to the unstructured planar films, as is typical in high-refractive-index-contrast waveguides [39]. Moreover, the waveguide losses exhibit greater wavelength dependence than the thin film losses based on the relative values measured at 633 and 1550 nm. Several mechanisms may introduce additional losses in our strip waveguides, including radiation of higher-order modes, scattering due to core-cladding interfacial roughness, and e-beam write-field stitching errors [39, 40]. Each loss mechanism theoretically scales inversely with wavelength, consistent with observation. We may reduce waveguide losses towards the thin-film values using alternative waveguide geometries [41], complimentary fabrication methods [42], or specialized e-beam writing strategies [43].
By investigating amorphous TiO$_2$ microphotonic features, we show that light is transmitted through waveguide bends with radii down to 2 $\mu$m and demonstrate TiO$_2$ optical couplers. To gain insight into the loss mechanisms of the investigated bend structures, we compare the simulated transmission properties of TiO$_2$ microphotonic bends with our experimental results. In Fig. 6(d) we show the calculated transmission through micro-bends as a function of bend radius. The total calculated loss includes the losses due to modal overlap mismatch at the interface between straight and bent waveguides and between 90°-bends of opposite direction, radiation losses from the 90°-bends, and the experimental propagation loss of 2.2 $\pm$ 0.4 dB/mm measured in 300-nm-wide amorphous TiO$_2$ waveguides. We observe a good agreement between the calculated and experimental data. In the calculated data, the primary contribution to the total loss is the modal overlap mismatch at the interfaces, and not radiative loss due to the bend itself. For example, we calculate a bend-bend transition loss of 0.75 dB compared with a radiation loss of 0.01 dB for a 90° bend with $r = 2$ $\mu$m. For micro-bends with $r \leq 2$ $\mu$m, the transmission can be improved by incorporating adiabatic transitions. We also expect that comparably small bend radii are feasible in anatase waveguides due to their similar dimensions and refractive indices. These results, combined with the high optical confinement in TiO$_2$ waveguides, demonstrate that TiO$_2$ devices can be densely integrated on photonic chips.

To compare our optical-coupler measurements to the theoretical splitting ratios, we calculate the coupling distance by solving for the even and odd TE-polarized modes in the investigated structures. We calculate effective indices of 1.919 and 1.885, respectively, for which coupled-mode theory predicts a 100% coupling length of 12 $\mu$m. This value is consistent with the experimentally observed coupling ratios and lengths when we account for the additional effective coupling length introduced by the adiabatic input and output regions (6 $\mu$m). We measure a splitting-ratio of approximately 90% for an effective length of 10 $\mu$m. Our data shows that we can achieve strong coupling over short lengths, allowing for small footprints for devices such as ring resonators.

6. Conclusion

In conclusion, we have fabricated amorphous and polycrystalline anatase TiO$_2$ thin films and strip waveguides with submicrometer widths. We observe light propagation over mm-length scales at 633 and 780 nm, and measure losses of 0.4 $\pm$ 0.2 dB/mm in amorphous and anatase strip-waveguides at 1550 nm. The consistency between simulated and experimental micro-bend and optical-coupler results suggest that realizing complex micro-scale TiO$_2$ photonic devices can be achieved using the techniques reported here. These results demonstrate TiO$_2$ to be a novel and promising platform for visible to infrared microphotonic devices.

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